

HA13539FP/549FP

Voice Coil Motor Driver IC

Description

The HA13539FP and the HA13549FP are IC that was developed for use as a voice coil motor driver in 12 V HDD applications. It provides the following functions and features.

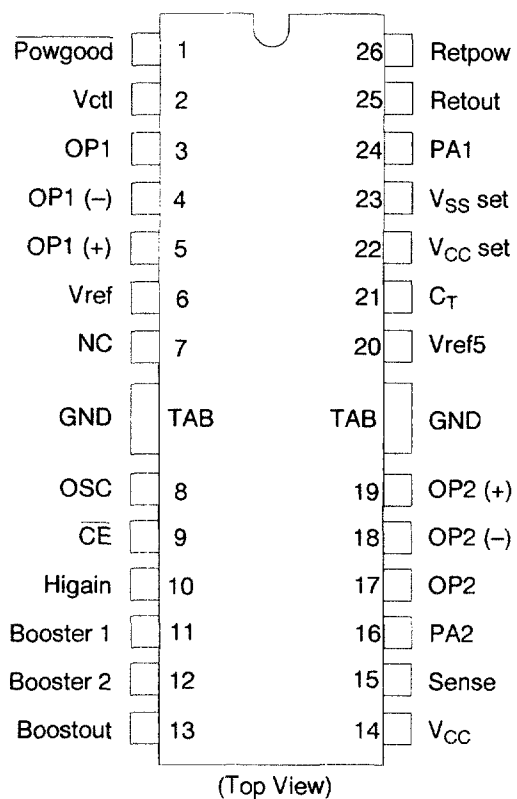
Features

- Low saturation voltage
- Low crossover distortion
- Less external components

Functions

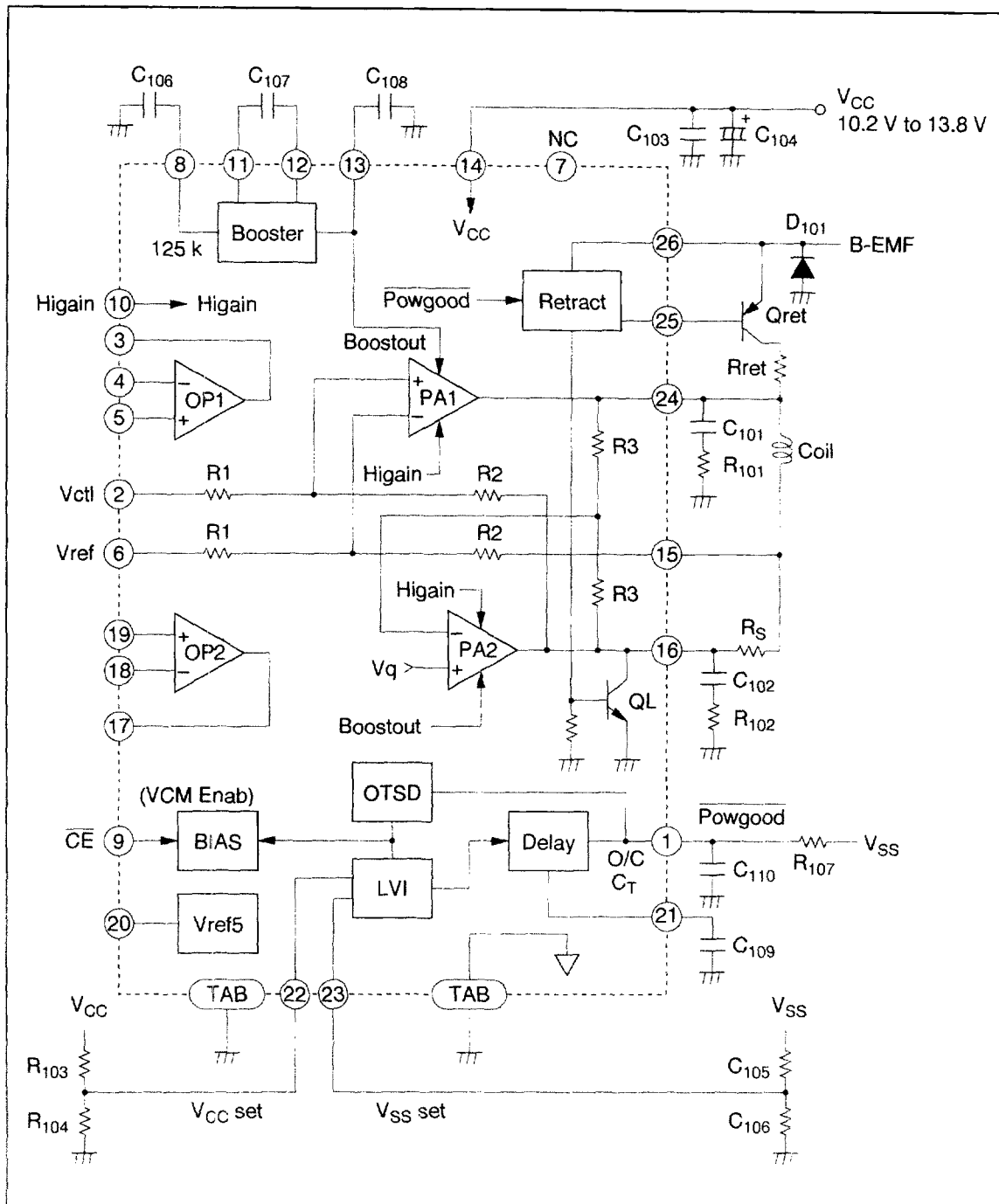
- 1.5 A BTL output amplifier (Dual gain)
- Auto-retraction circuit
- Two independent operational amplifiers
- 5 V reference voltage
- Thermal protection circuit OTSD
- Two under-voltage protection circuits LVI

Pin Arrangement



HA13539FP/549FP

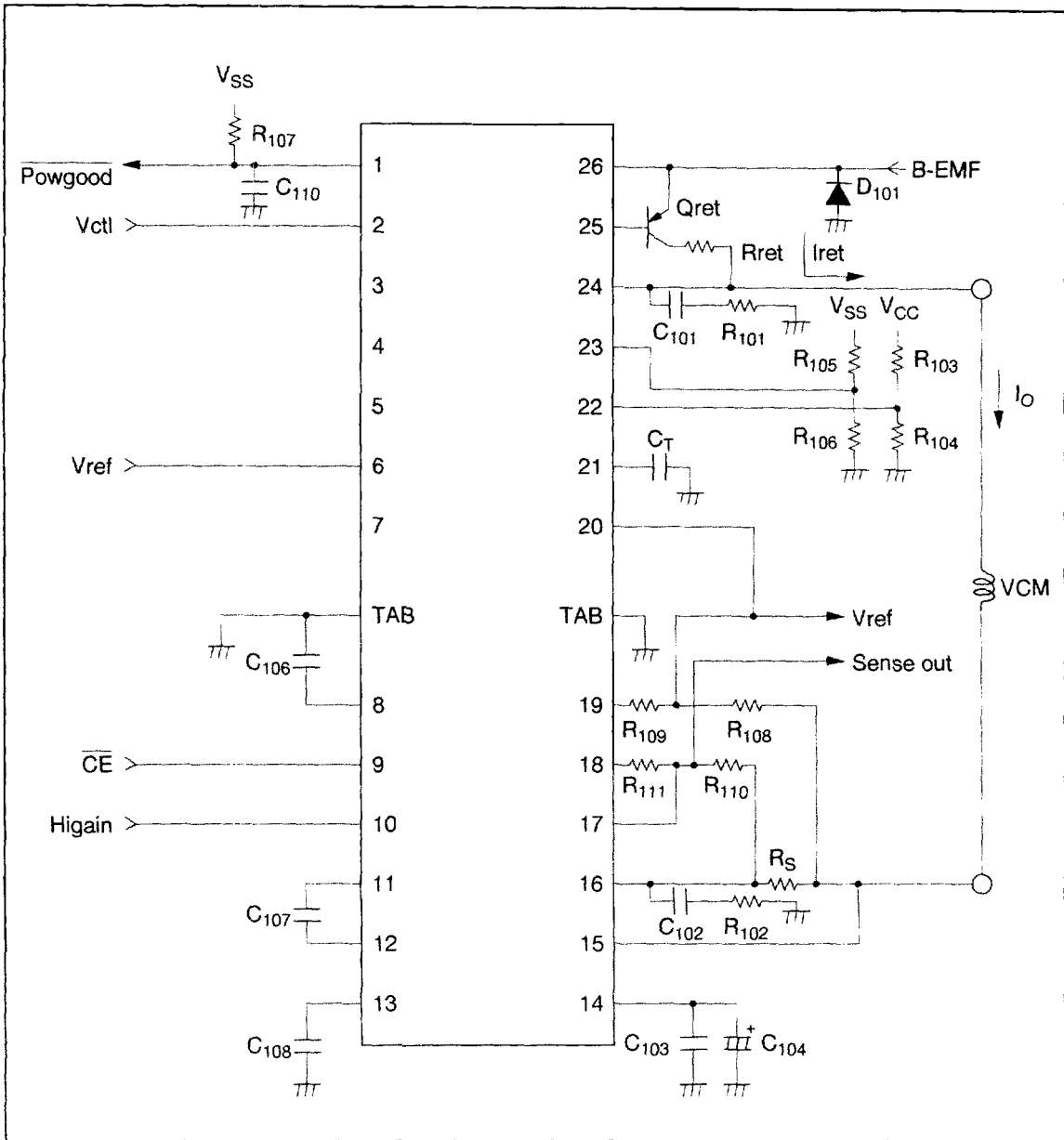
Block Diagram



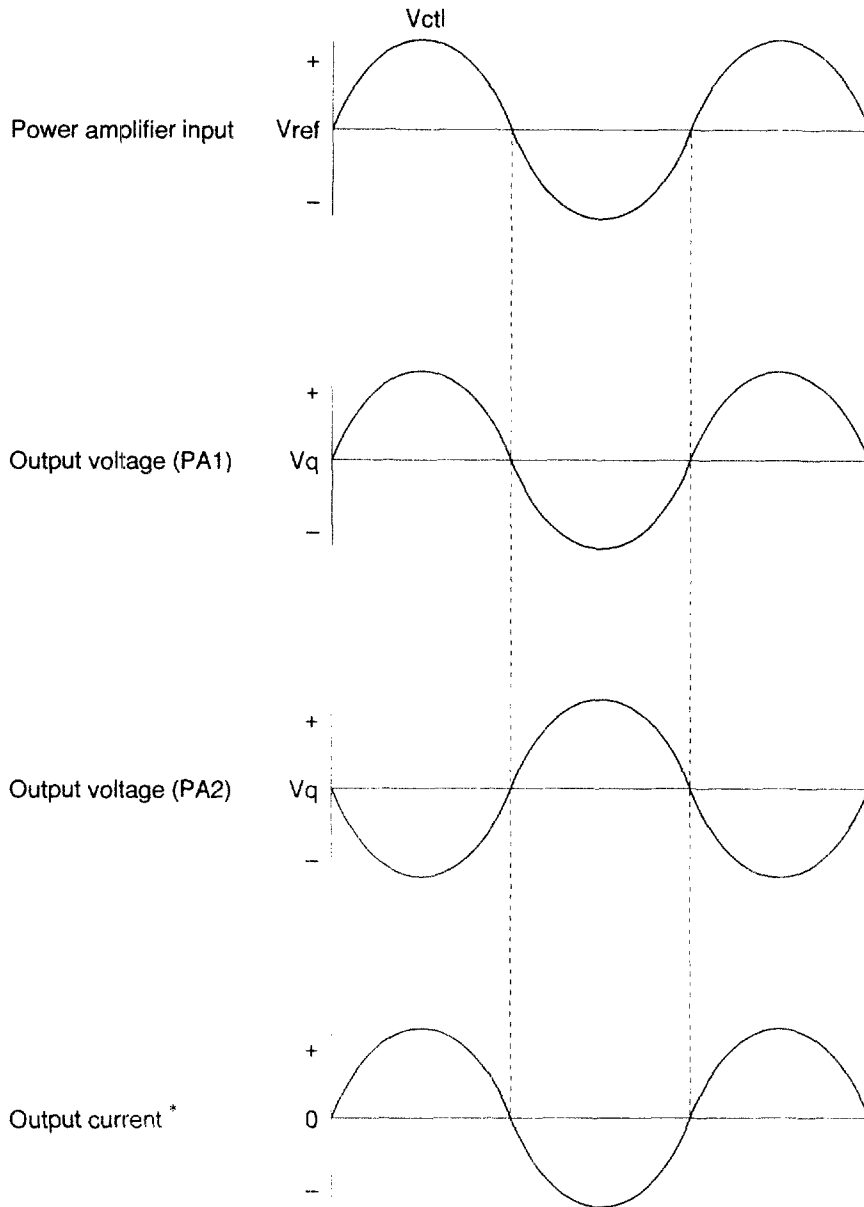
Pin Assignment

Pin No.	Symbol	Function
1	$\overline{\text{Powgood}}$	Abnormal state monitor. Low: Normal state, High impedance: Abnormal state. Open collector output
2	V_{ctl}	Power amplifier (+) input. PA1 output reference.
3	OP1	Operational amplifier that operates when $V_{\text{CC}} > 10 \text{ V}$ independent of the $\overline{\text{CE}}$ pin. Can be used for input filter.
4	OP1 (-)	OP1 (-) input Must be shorted to ground when unused.
5	OP1 (+)	OP1 (+) input
6	V_{ref}	Power amplifier (-) input. PA1 output reference.
8	OSC	Used with the booster (charge pump) and as an oscillator frequency adjustment.
9	$\overline{\text{CE}}$	Chip enable. Low: Enable, High: Disable
10	Higain	Power amplifier gain switch. Low: Low gain, High: High gain
11	Booster 1	Booster (charge pump) pulse input
12	Booster 2	Booster (charge pump) pulse output
13	Boostout	Booster output. Power amplifier pre-driver power supply
14	V_{CC}	Power supply
15	Sense	Power amplifier current sense
16	PA2	PA2 output
17	OP2	Operational amplifier that operates when $V_{\text{CC}} > 10 \text{ V}$ independent of the $\overline{\text{CE}}$ pin. Can be used as a sensor amplifier.
18	OP2 (-)	OP2 (-) input Must be shorted to ground when unused.
19	OP2 (+)	OP2 (+) input
20	V_{ref5}	5 V Reference voltage. Use power amplifier reference voltage.
21	C_{T}	$\overline{\text{Powgood}}$ falling edge delay time setting
22	V_{CCset}	V_{CC} side LVI operating voltage (V_{sd1}) setting. Must be shorted to V_{CC} if unused.
23	V_{SSset}	V_{SS} side LVI operating voltage (V_{sd2}) setting. Must be shorted to V_{CC} or V_{SS} if unused.
24	PA1	PA1 output
25	Retout	Retractor external PNP base current supply
26	Retpow	Retractor power supply. Can be used the spindle motor output.

Application



Timing Chart



Notes: These waveforms are for input frequencies less than 1 kHz.

* Current flowing from PA1 to PA2 is indicated as positive (+), and current flowing from PA2 to PA1 is indicated as negative (-).

Truth Table 1

Inputs				Outputs			
V_{CC}	V_{SS}	$\overline{CE}^2$	Higain ^{*2}	PA1	PA2	Retout	$\overline{Powgood}$
$\leq V_{sd1}^{*1}$	$\leq V_{sd2}^{*1}$	X	X	Disable	$V_{sat}L^{*3}$	I_{ret}^{*3}	I_{ret}^{*3}
$\leq V_{sd1}$	$> V_{sd2}$						
$> V_{sd1}$	$\leq V_{sd2}$						
$> V_{sd1}$	$> V_{sd2}$	H	X	Disable	Disable	Z	L
		L	H	High gain ^{*1}	High gain ^{*1}	Z	L
			L	Low gain ^{*1}	Low gain ^{*1}	Z	L
$> V_{sd1}$	$> V_{sd2}$	X	$(T_j > T_{sd})$	Disable	$V_{sat}L^{*3}$	I_{ret}^{*3}	Z

Truth Table 2

Inputs	Outputs	
V_{CC}	OP1,OP2	Vref5
$< 7V$	Disable	Disable
8 V to 12 V	Enable	Enable

- Notes: 1. See the external components table.
 2. Z = High impedance
 H = High voltage level
 L = Low voltage level
 X = Irrelevant
 3. See the electrical characteristics table.

External Components

Part No.	Recommended Value	Purpose	Note
R ₁₀₁ , R ₁₀₂	2.2 Ω	Power amplifier output stabilization	
R ₁₀₃ , R ₁₀₄	—	LVI voltage setting (V _{CC})	1
R ₁₀₅ , R ₁₀₆	—	LVI voltage setting (V _{SS})	2
R ₁₀₇	—	Powgood pull-up	
R ₁₀₈ to R ₁₁₁	—	Output sense amplifier gain setting	
R _S	1.0 Ω	Power amplifier output current detection	3
R _{ret}	—	Retractor current limiter	4
Q _{ret}	—	Retractor	4
C ₁₀₁ , C ₁₀₂	0.1 μF	Power amplifier output stabilization	
C ₁₀₃ , C ₁₀₄	0.1 μF, 4.7 μF	Power supply stabilization	
C ₁₀₆	820 pF	Booster (oscillation)	
C ₁₀₇ , C ₁₀₈	0.1 μF, 2.2 μF	Booster	
C ₁₀₉	0.01 μF	Powgood delay setting	5
C ₁₁₀	0.0022 μF	Powgood filter	
D ₁₀₁	V _F < 0.75 V (I _F = 0.5 A)	B-EMF clamp	

Notes: 1. The LVI1 (V_{CC}) operating voltage (V_{sd1}) and hysteresis (V_{hys1}) are determined by the following formulas.

$$V_{sd1} = \left(1 + \frac{R_{103}}{R_{104}}\right) \cdot V_{ref1} \text{ (V)} \quad (\text{Set } V_{sd1} \text{ to be 9.0 V or higher.})$$

$$V_{hys1} = \left(1 + \frac{R_{103}}{R_{104}}\right) \cdot V_{hys1} \text{ (V)} \quad V_{ref1}, V_{hys1} : \text{ See the electrical characteristics table.}$$

2. The LVI2 (V_{SS}) operating voltage (V_{sd2}) and hysteresis (V_{hys2}) are determined by the following formulas.

$$V_{sd2} = \left(1 + \frac{R_{105}}{R_{106}}\right) \cdot V_{ref2} \text{ (V)} \quad (\text{Set } V_{sd2} \text{ to be 3.0 V or higher.})$$

$$V_{hys2} = \left(1 + \frac{R_{105}}{R_{106}}\right) \cdot V_{hys2} \text{ (V)} \quad V_{ref2}, V_{hys2} : \text{ See the electrical characteristics table.}$$

3. The relationship between the PA output current (I_O) and input voltage (V_{ctl}) is determined by the following formula.

$$I_O = \frac{(V_{ctl} - V_{ref}) G_{ctl}}{R_S} = \frac{(V_{ctl} - V_{ref}) \cdot g_m \cdot R'_S}{R_S}$$

Where: G_{ctl}: g_m·R'_S' (See the electrical characteristics table.)
V_{ref}: PA1 reference voltage

4. The retract current (I_{ret}) is determined by the following formula.

$$I_{ret} = \frac{V_{retpow} - V_{retsat} - V_{satL}}{R_L + R_S + R_{ret}}$$

Where: V_{retpow}: Retpow voltage
V_{retsat}: Q_{ret} saturation voltage
R_L: Load resistance
V_{satL}: PA2 lower side saturation voltage (See the electrical characteristics table.)

5. The Powgood delay time (T_{por}) is determined by the following formulas.

$$T_{porH} = C_T \cdot V_{th}/I_{cha}$$

$$T_{porL} \leq C_T (V_{CC} - V_{th})/I_{dis}$$

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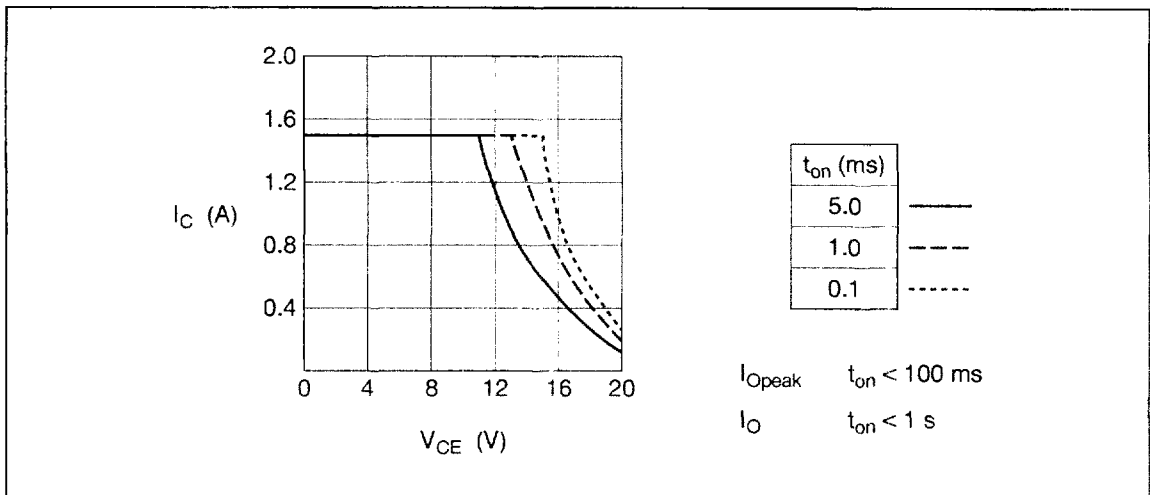
Absolute Maximum Ratings

Item	Symbol	HA13539FP	HA13549FP	Unit	Note
Power supply voltage	V_{CC}	15	15	V	1
Peak output current	I_{Opeak}	1.5	1.5	A	2
Steady-state output current	I_O	1.0	1.0	A	2
Retract current	I_{ret}	0.2	0.2	A	3
Input voltage	V_{in}	V_{CC}	V_{CC}	V	
Allowable power dissipation	P_T	6.0 ($T_C = 100^\circ\text{C}$)	6.0 ($T_C = 100^\circ\text{C}$)	W	4
Junction temperature	T_j	+150	+150	$^\circ\text{C}$	5
Storage temperature	T_{stg}	-55 to +125	-55 to +125	$^\circ\text{C}$	

Notes: 1. The operating voltage range is as follows:

$$V_{CC} = 10.2 \text{ V to } 13.8 \text{ V}$$

2. ASO of each output transistor is shown below. Operating locus must be within the ASO.



3. Applies to the PA2 lower side transistor. (Q_{ret})

4. Permitted value at $T_C = 100^\circ\text{C}$. Thermal resistance is shown below.

$$\theta_{j-c} \leq 8 \text{ }^\circ\text{C/W}$$

$$\theta_{j-a} \leq 35 \text{ }^\circ\text{C/W (when a 6-layer printed circuit board is used)}$$

$$\theta_{j-a} \leq 62 \text{ }^\circ\text{C/W (when a glass epoxy printed circuit board is used with a wiring density of 20\%)}$$

5. The junction operating temperature range is as follows.

$$T_{jopr} = 0 \text{ }^\circ\text{C to } 125 \text{ }^\circ\text{C}$$

Electrical Characteristics ($T_a = 25^\circ\text{C}$, $V_{CC} = 12\text{ V}$, $V_{SS} = 5\text{ V}$)

Item		Symbol	Min	Typ	Max	Unit	Test Condition	Applicable Pins	Note
Quiescent current		I_{CC0}	—	3.5	5.0	mA	$\overline{CE} = H$	14	
		I_{CC1}	—	15	20	mA	$\overline{CE} = L, V_{SS} = 5V$		
		I_{retpow}	—	50	70	mA	$\overline{CE} = L, V_{SS} = 0V$ $V_{\text{retpow}} = 5V$	26	
$\overline{CE}$, Higain	Input current	I_{in1}	—	—	±10	μA		9, 10	
	Input high voltage	V_{ih1}	2.0	—	—	V			
	Input low voltage	V_{il1}	—	—	0.8	V			
PA1, PA2	Input resistance	$R_{\text{in}} (H)$	15 (22.5)	20 30	25 37.5)	kΩ	Higain = H	2, 6	
		$R_{\text{in}} (L)$	30	40	50	kΩ	Higain = L		
	Common mode input voltage range	$V_{\text{cm}} (H)$	0	—	V_{CC} −2.0	V	Higain = H		
		$V_{\text{cm}} (L)$	0	—	V_{CC} −2.0	V	Higain = L		
	Output quiescent-voltage	V_q	5.6	6.0	6.4	V	$R_L = 10\ \Omega$, $R_S = 1.0\ \Omega$	16, 24	
	Output offset voltage (PA2-sense)	$V_{\text{ofs}} (H)$	—	—	±5	mV	Higain = H, $R_S = 1.0\ \Omega$, $R_L = 10\ \Omega$ $V_{\text{ctl}} = V_{\text{ref}} = 6.0\text{ V}$		
		$V_{\text{ofs}} (L)$	—	—	±3	mV	Higain = L, $R_S = 1.0\ \Omega$, $R_L = 10\ \Omega$ $V_{\text{ctl}} = V_{\text{ref}} = 6.0\text{ V}$		
	Output saturation voltage	V_{sat1}	—	0.8	1.1	V	$I_O = 0.8\text{ A}$		1
		V_{sat2}	—	0.4	0.55	V	$I_O = 0.4\text{ A}$		
	Output leak current	I_{CER}	—	—	±100	μA	$V_{CE} = 15\text{ V}$		2
	Transfer gain	$g_m (H)$	1.75 (0.86)	1.87 0.93	1.99 1.00)	A/V	Higain = H, $R'_S = 1.0\ \Omega$	2, 6, 16, 24	3
		$g_m (L)$	0.42	0.46	0.50	A/V	Higain = L, $R'_S = 1.0\ \Omega$		
	Gain bandwidth (resistive load)	B (H)	—	45 (70)	—	kHz	Higain = H $R_L = 10\ \Omega$, $R_S = 1.0\ \Omega$		4
		B (L)	—	90	—	kHz	Higain = L $R_L = 10\ \Omega$, $R_S = 1.0\ \Omega$		
Retract	Retpow voltage	V_{retpow}	0.8	—	—	V	$I_{\text{retout}} = 0.1\text{ mA}$	26	
	Retout output current	I_{retout}	5.0	9.0	—	mA	$V_{\text{retpow}} = 3\text{ V}$	25	
	QL saturation voltage	V_{satL}	—	0.1	0.25	V	$I_{\text{ret}} = 0.1\text{ A}$ $V_{\text{retpow}} = 3\text{ V}$	16	
OP1, OP2	Input current	I_{inop}	—	—	±500	nA		4, 5	
	Input offset voltage	V_{osop}	—	—	±7	mV		18, 19	

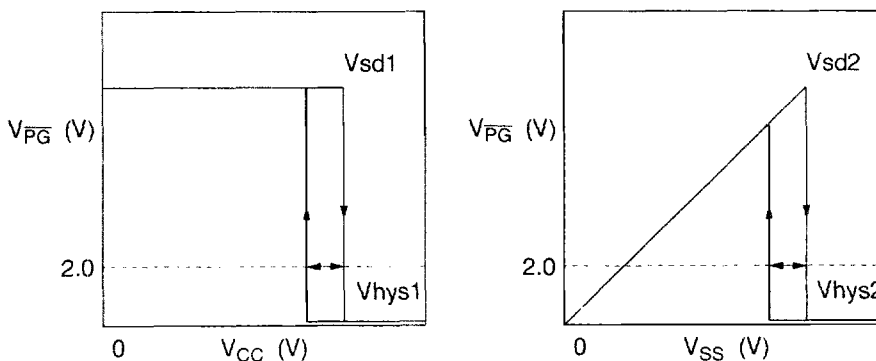
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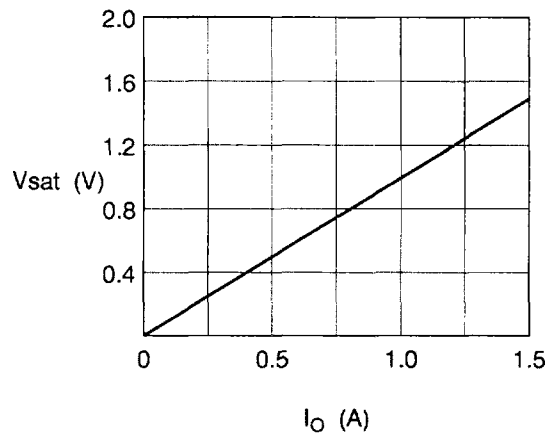
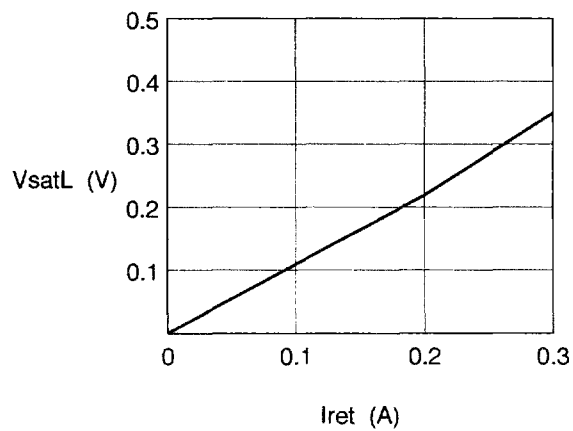
Electrical Characteristics ($T_a = 25^\circ\text{C}$, $V_{CC} = 12\text{ V}$, $V_{SS} = 5\text{ V}$) (cont.)

Item		Symbol	Min	Typ	Max	Unit	Test Condition	Applicable Pins	Note
OP1, OP2	Common mode input voltage range	V_{cmop}	0	—	$V_{CC} - 1.8$	V		4, 5, 18, 19	
	Output high voltage	V_{ohop}	$V_{CC} - 1.3$	—	—	V	$I_{out} = 1.0\text{ mA}$	3, 17	
	Output low voltage	V_{olop}	—	—	1.1	V	$I_{out} = 1.0\text{ mA}$		
	Open loop gain	G_{op}	—	41	—	dB	$f = 10\text{ kHz}$		4
	Gain bandwidth	B_{op}	—	1.5	—	MHz	$G_{op} = 0\text{ dB}$		
Powgood	Output leak current	I_{leak}	—	—	± 10	μA	$V_{oh} = 15\text{ V}$	1	
	Output low voltage	V_{ol}	—	0.1	0.4	V	$I_{ol} = 1\text{ mA}$		
Vref5	Output voltage	V_{ref5}	4.75	4.9	5.05	V	$I_O = 20\text{ mA}$	20	
	Output resistance	R_{out}	—	—	5	Ω	$I_O = 20\text{ mA}$		
LVI	Reference voltage	V_{ref1}	1.32	1.36	1.40	V	$R_{103} = 62\text{ k}\Omega$	22, 23	
		V_{ref2}	1.28	1.32	1.36	V	$R_{104} = 10\text{ k}\Omega$		
	Hysteresis	V_{hys1}	40	80	100	mV	$R_{105} = 18\text{ k}\Omega$		
		V_{hys2}	60	105	130	mV	$R_{106} = 10\text{ k}\Omega$		
Delay	Threshold voltage	V_{th}	—	2.5	—	V		21	
	Ct charge current	I_{cha}	—	10	—	μA			
	Ct discharge current	I_{dis}	1.0	1.8	—	mA			
OTSD	Operating temperature	T_{sd}	125	150	—	$^\circ\text{C}$			4
	Hysteresis	T_{hys}	—	25	—	$^\circ\text{C}$			

- Notes: 1 The output saturation voltage is the sum of the upper and lower saturation voltages.
2 The value is output transistor only, not include Feed back resistance etc.
3 The value in parentheses apply to the HA13549FP.
4 These are design center values and are not (and cannot be) tested in the mass production products.

The LVI circuit has the hysteresis, and it is shown below.



Main Characteristics**Figure 1. Output Saturation Voltage vs. Output Current****Figure 2. Lower Side Saturation Voltage vs. Retractor Current**

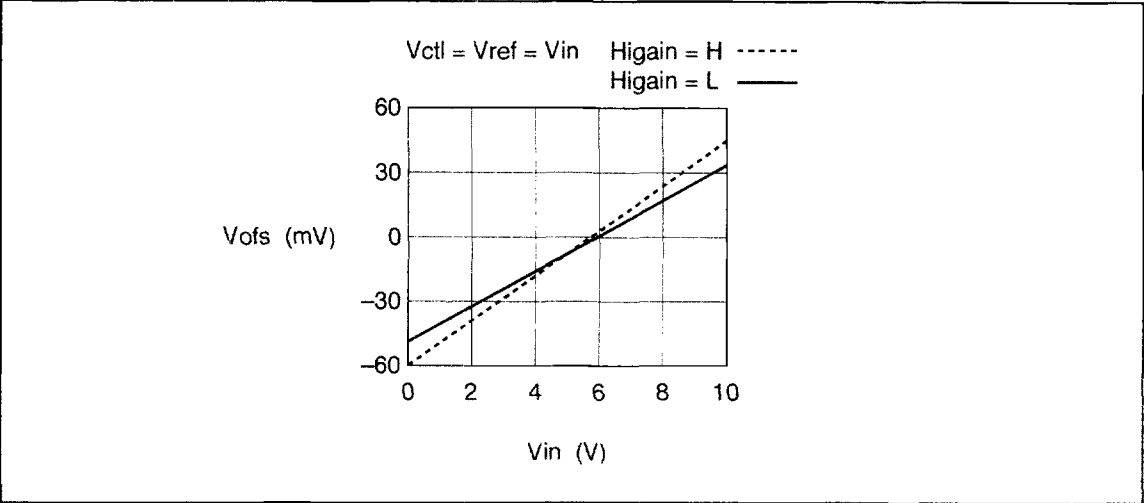


Figure 3. Input Voltage vs. Output Offset Voltage

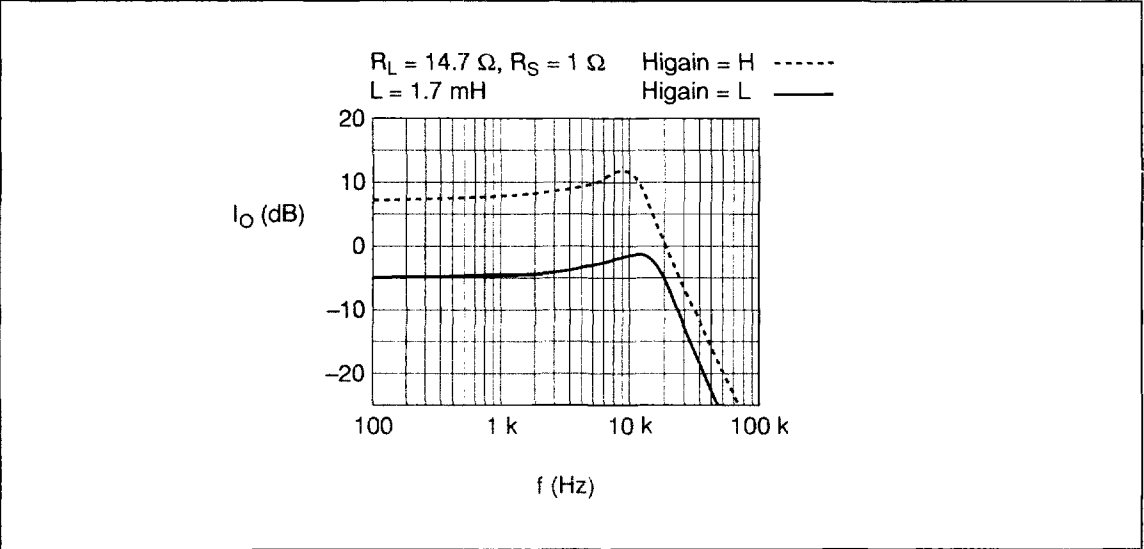


Figure 4. Output Current Frequency Characteristics